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APPLICATION NO.	FI	LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/087,660	10/087,660 03/01/2002		Michael John Towler	YAMAP0804US	7895
7:	590	12/01/2004		EXA	MINER
Neil A. DuCh	ez		DUONG, THOI V		
Renner, Otto, E	Boisselle	e & Sklar		<u></u>	
1621 Euclid Av			ART UNIT	PAPER NUMBER	
Cleveland OH 44115				2871	

DATE MAILED: 12/01/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)
	10/087,660	TOWLER ET AL.
Office Action Summary	Examiner	Art Unit
	Thoi V Duong	2871
The MAILING DATE of this communication apperiod for Reply	pears on the cover sheet with the o	correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a rep - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailine earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tir oly within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed /s will be considered timely. It the mailing date of this communication. ED (35 U.S.C. § 133).
Status		
1)⊠ Responsive to communication(s) filed on 19 J 2a)□ This action is <b>FINAL</b> . 2b)⊠ This	l <u>uly 2004</u> . s action is non-final.	
3) Since this application is in condition for allowards closed in accordance with the practice under	•	
Disposition of Claims		
4) ⊠ Claim(s) 1.3-20 and 24-26 is/are pending in the 4a) Of the above claim(s) is/are withdra 5) □ Claim(s) is/are allowed.  6) ⊠ Claim(s) 1.3-20 and 24-26 is/are rejected.  7) □ Claim(s) is/are objected to.  8) □ Claim(s) are subject to restriction and/or is/are objected.	awn from consideration.	
Application Papers		
9) The specification is objected to by the Examination 10) The drawing(s) filed on is/are: a) acceptable and applicant may not request that any objection to the Replacement drawing sheet(s) including the correct of the oath or declaration is objected to by the Examination.	cepted or b) objected to by the drawing(s) be held in abeyance. Section is required if the drawing(s) is ob	e 37 CFR 1.85(a). ojected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list	nts have been received. Its have been received in Applicatority documents have been received (PCT Rule 17.2(a)).	ion No ed in this National Stage
Attachment(s)	4) 🔲 Interview Summary	, (PTO.413)
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date <u>0904</u>.</li> </ol>	Paper No(s)/Mail D	

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### **DETAILED ACTION**

#### Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on July 19, 2004 has been entered.

Accordingly, claim 1 was amended and claims 2 and 21-23 were cancelled.

Currently, claims 1, 3-20 and 24-26 are pending in this application.

# Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1, 3-10, 12-17, 19 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Acosta et al. (EP 0996028A2) in view of Funada et al. (USPN 4,232,947).

Re claims 1, 3 and 4, as shown in Fig. 1, Acosta et al. discloses a liquid crystal device comprising a nematic liquid crystal 3, voltage means for applying a voltage across said liquid crystal, and two substrates 1, 1' each provided with an alignment

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layer 2, 2' (col. 1, paragraphs 1-5), wherein, as illustrated in Fig. 9, a modification of Fig. 7:

said liquid crystal is sandwiched between said two substrates;

said nematic liquid crystal can be placed in at least one operating state and at least one non-operating state (cols. 1 and 2, paragraphs 8 and 9);

at least one of said alignment layers is provided with a plurality of surface protrusions 8, 8' formed from an anisotropic material as shown in Fig. 9 (cols. 13 and 14, paragraphs 81 and 82); and

said protrusions affect alignment both near the surface where a high pre-tilt in region B is produced and within the bulk of the liquid crystal where the V-state grows from region B into adjacent regions A and C (col. 12, paragraph 73 and col. 13, paragraph 81).

Re claims 5 and 16, Acosta et al. discloses that at least some of said protrusions nucleate said liquid crystal into said operating state from said non-operating state when said voltage exceeds a threshold value and said operating and non-operating states are topologically distinct from each other (cols. 1 and 2, paragraph 8 and 9; col. 4, paragraph 22; and col. 12, paragraph 73).

Re claim 6, Acosta et al. discloses that at least some of said protrusions isolate said operating state from said non-operating state or from another operating state (col. 12, paragraph 73).

Re claims 7 and 8, Acosta et al. discloses that said liquid crystal is divided into a plurality of pixels each having an active region, and wherein the active region of each

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said pixel contains, or overlaps with, or lies adjacent or close to, at least one of said protrusions, so that nucleation occurs within said active region and wherein each said pixel is surrounded by at least one of said protrusions, so that the pixel is isolated (Fig. 10 and col. 14, paragraph 83).

Re claims 9 and 10, Acosta et al. discloses that said nematic liquid crystal is a picell or splay bend device (SBD) (col. 1, paragraphs 1-3).

Re claim 15, Acosta et al. discloses that the anisotropic protrusions are formed from a polymerisable reactive mesogen (cols. 13 and 14, paragraphs 81 and 82).

Re claim 17, Acosta et al. discloses that when said voltage is substantially zero different regions of said liquid crystal exist in first non-operating state (region B) and second non-operating state (region A or C), and the first non-operating state is stabilized by said anisotropic protrusions 8, 8' as illustrated in Fig. 9, which is a modification of the device shown in Fig. 7, wherein said first and second non-operating states are V and H states respectively and wherein said first non-operating state is the same state as said operating state (col. 12, paragraph 73).

Re claim 20, Acosta also discloses a method of producing the liquid crystal device in Fig. 9 comprising the steps of forming a reactive mesogen layer 8, 8' on substrates 1, 1', curing said layer by irradiating said layer with UV light through a mask to leave said one of said substrates coated with anisotropic protrusions, and forming a liquid crystal cell by sandwiching nematic liquid crystal material between said two substrates (col. 14, paragraph 82).

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Re claim 24, the protrusions 8, 8' in Fig. 9 of Acosta et al. are trapezoidal anisotropic protrusions.

Acosta et al. discloses a liquid crystal device that is basically the same as that recited in claims 1, 3 and 4 except for protrusions having a height which is at least 10% or 20% or substantially 50% of the thickness of the liquid crystal.

As shown in Figs. 4-6, Funada et al. discloses a nematic liquid crystal device comprising a multiplicity of protrusions having an anisotropic profile and the height of 10 through 10,000 Angstroms (1 micrometer) for the purpose of regulating or defining the alignment of the liquid crystal molecules so as to eliminate the degeneration states of the liquid crystal molecules (col. 2, lines 61-66).

As known in the art, the two substrates of the liquid crystal display device are typical 1-6 micrometers apart. Accordingly, if the protrusions have a height of 0.6 or 1 micrometer and the two substrates of the LCD device is 6 or 5 micrometers apart, respectively, the protrusions will have the height which is at least 10% or 20% of the thickness of the liquid crystal. Similarly, if the protrusions have a height of 1 micrometer and the two substrates of the LCD device is 2 micrometers apart, the protrusions will have the height which is substantially 50% of the thickness of the liquid crystal.

Re claims 12-14, Funada et al. discloses that the protrusions are tilted anisotropy protrusions (col. 3, lines 32-46) or twisted anisotropy protrusions (col. 3, line 61 through col. 4, line 30).

Finally, re claims 25 and 26, the protrusions in Fig. 4 of Funada et al. are triangular or mitre-shaped anisotropic protrusions.

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Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the device of Acosta et al. with the teaching of Funada et al. by forming anisotropic protrusions having a height which is at least 10% or 20% or substantially 50% of the thickness of the liquid crystal for the purpose of regulating or defining the alignment of the liquid crystal molecules so as to eliminate the degeneration states of the liquid crystal molecules (col. 2, lines 61-66).

4. Claims 11 and 18 rejected under 35 U.S.C. 103(a) as being unpatentable over Acosta et al. (EP 0996028A2) in view of Funada et al. (USPN 4,232,947) as applied to claims 1, 3-10, 12-17, 19 and 20 above, and further in view of Ulrich et al. (USPN 6,618,113 B1).

The liquid crystal device of Acosta et al. as modified in view of Funada et al. above includes all that is recited in claims 11 and 18 except for a bistable twisted nematic (BTN).

As shown in Figs. 12 and 16, Ulrich et al. discloses a liquid crystal device comprising a bistable twisted nematic (BTN) liquid crystal layer 23 and twisted anisotropic spacer walls 10 (col. 7, lines 35-46 and col. 9, lines 43-47) so as to avoid substantial reduction in contrast ratio (col. 4, lines 27-32).

Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to further modify the liquid crystal device of Acosta et al. with the teaching of Ulrich et al. by employing a BTN liquid crystal and twisted anisotropic protrusions to create a first non-operating state as T state and improve contrast ratio for the display (col. 4, lines 27-32).

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# Response to Arguments

5. Applicants' arguments filed July 19, 2004 have been fully considered but they are not persuasive.

Applicants argued that Acosta et al. and Funada et al. fail to teach or suggest protrusions to affect alignment near the surface and within the bulk of the liquid crystal layer as recited in claim 1. The Examiner disagrees with Applicant's remarks since, as shown in Fig. 9, Acosta et al. discloses the protrusions 8 affecting alignment both near the surface in region B where the V-state of high pre-tilt is produced (col. 13, paragraph 81) and within the bulk of the liquid crystal where the V-state grows from the region B into the adjacent regions A and C when a voltage is applied across the liquid crystal layer (col. 12, paragraph 73). Thus, the combination of Acosta et al. and Funada et al. still meet all limitations recited in the claims.

#### Conclusion

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thoi V. Duong whose telephone number is (571) 272-2292. The examiner can normally be reached on Monday-Friday from 8:30 am to 4:30 pm. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim, can be reached at (571) 272-2293.

Thoi Duong

11/22/2004 TD

TARIFUR R. CHOWDHURY

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